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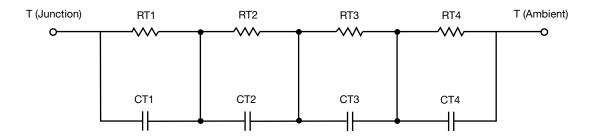
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in PSpice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the PSpice simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the PSpice Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK	-C VALUES FOR TANK CONFIGURATION				
	THERMAL RES	SISTANCE (°C/W)			
Junction to	Ambient	Case	Foot		
RT1	n/a	42.7770m	n/a		
RT2	n/a	63.5712m	n/a		
RT3	n/a	353.3086m	n/a		
RT4	n/a	240.3432m	n/a		
	THERMAL CAPAC	ITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot		
CT1	n/a	67.9733m	n/a		
CT2	n/a	2.6416m	n/a		
CT3	n/a	73.2516m	n/a		
CT4	n/a	15.8741m	n/a		

Note

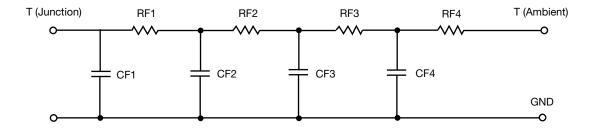
• n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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R-C THERMAL MODEL FOR FILTER CONFIGURATION



THERMAL RESISTANCE (°C/W)				
Junction to	Ambient	Case	Foot	
RF1	n/a	111.9788m	n/a	
RF2	n/a	340.4747m	n/a	
RF3	n/a	203.9680m	n/a	
RF4	n/a	43.5785m	n/a	
	THERMAL CAPAC	ITANCE (Joules/°C)		
Junction to	Ambient	Case	Foot	
CF1	n/a	2.5277m	n/a	
CF2	n/a	9.8874m	n/a	
CF3	n/a	89.7877m	n/a	
CF4	n/a	4.5674m	n/a	

Note

• n/a indicates not applicable





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